CMOS Digital Integrated Circuits Silicon Monolithic

# 7UL1G04FU

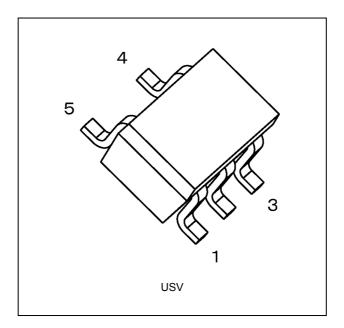
#### 1. Functional Description

• Inverter

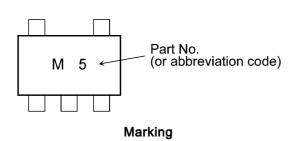
#### 2. Features

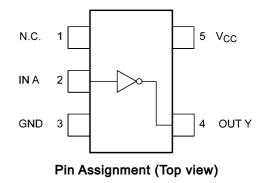
- (1) Wide operating temperature range:  $T_{opr} = -40$  to 125 °C
- (2) High output current:  $\pm 8.0 \text{ mA}$  (min) at V<sub>CC</sub> = 3.0 V
- (3) Super high speed operation:  $t_{pd}$  = 2.5 ns (typ.) at V<sub>CC</sub> = 3.3 V, C<sub>L</sub> = 15 pF
- (4) Operation voltage range:  $V_{CC}$  = 0.9 to 3.6 V
- (5) 3.6 V tolerant inputs
- (6) 3.6 V power down protection output

#### 3. Packaging



4. Marking and Pin Assignment





Start of commercial production 2018-08

#### 5. IEC Logic Symbol



#### 6. Truth Table

Input A	Output Y
L	Н
Н	L

#### 7. Absolute Maximum Ratings (Note) (Unless otherwise specified, T<sub>a</sub> = 25 °C)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V <sub>CC</sub>		-0.5 to 4.6	V
Input voltage	V <sub>IN</sub>		-0.5 to 4.6	V
DC output voltage	V <sub>OUT</sub>	(Note 1)	-0.5 to 4.6	V
		(Note 2)	-0.5 to V <sub>CC</sub> + 0.5	]
Input diode current	I <sub>IK</sub>		-20	mA
Output diode current	I <sub>ОК</sub>	(Note 3)	-20	mA
DC output current	I <sub>OUT</sub>		±25	mA
V <sub>CC</sub> /ground current	I <sub>CC</sub>		±50	mA
Power dissipation	PD		200	mW
Storage temperature	T <sub>stg</sub>		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1:  $V_{CC}$  = 0 V

Note 2: High (H) or Low (L) state. I<sub>OUT</sub> absolute maximum rating must be observed.

Note 3: V<sub>OUT</sub> < GND

#### 8. Operating Ranges (Note)

Characteristics	Symbol	Note	Test Condition	Rating	Unit
Supply voltage	V <sub>CC</sub>		_	0.9 to 3.6	V
Input voltage	V <sub>IN</sub>		_	0 to 3.6	V
Output voltage	V <sub>OUT</sub>	(Note 1)	_	0 to 3.6	V
		(Note 2)	_	0 to V <sub>CC</sub>	1
Output current	I <sub>OH</sub> ,I <sub>OL</sub>		V <sub>CC</sub> = 3.0 to 3.6 V	±8.0	mA
			V <sub>CC</sub> = 2.3 to 2.7 V	±4.0	]
			V <sub>CC</sub> = 1.65 to 1.95 V	±3.0	
			V <sub>CC</sub> = 1.4 to 1.6 V	±1.7	
			V <sub>CC</sub> = 1.1 to 1.3 V	±0.3	]
			V <sub>CC</sub> = 0.9 V	±0.02	
Operating temperature	T <sub>opr</sub>		_	-40 to 125	°C
Input rise and fall time	dt/dv		$V_{IN}$ = 0.8 to 2.0 V, $V_{CC}$ = 3.0 V	0 to 10	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.

Note 1:  $V_{CC} = 0 V$ 

Note 2: High (H) or Low (L) state.

#### 9. Electrical Characteristics

#### 9.1. DC Characteristics (Unless otherwise specified, T<sub>a</sub> = 25 °C)

Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Тур.	Max	Unit
High-level input voltage	V <sub>IH</sub>	—		0.9	V <sub>CC</sub>	_	_	V
				1.1 to 1.3	$V_{CC}  imes 0.70$		_	1
				1.4 to 1.6	$V_{CC}  imes 0.65$	_	_	
				1.65 to 1.95	$V_{CC} \times 0.65$		—	
				2.3 to 2.7	1.7	_	—	
				3.0 to 3.6	2.0	_	—	
Low-level input voltage	VIL	—		0.9	—	_	GND	V
				1.1 to 1.3	_	_	$V_{CC} \times 0.30$	
				1.4 to 1.6	_	_	$V_{CC} \times 0.35$	
				1.65 to 1.95	—	_	$V_{CC} \times 0.35$	
				2.3 to 2.7	_	_	0.7	
				3.0 to 3.6	_	_	0.8	
High-level output voltage	V <sub>OH</sub>	$V_{IN} = V_{IL}$	I <sub>OH</sub> = -0.02 mA	0.9	0.75		—	V
			I <sub>OH</sub> = -0.3 mA	1.1 to 1.3	$V_{CC} \times 0.75$		_	
			I <sub>OH</sub> = -1.7 mA	1.4 to 1.6	$V_{CC} \times 0.75$		_	]
			I <sub>OH</sub> = -3.0 mA	1.65 to 1.95	V <sub>CC</sub> -0.45		_	]
			I <sub>OH</sub> = -4.0 mA	2.3 to 2.7	2.0		_	
			I <sub>OH</sub> = -8.0 mA	3.0 to 3.6	2.48		_	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub>	I <sub>OL</sub> = 0.02 mA	0.9	—		0.1	V
			I <sub>OL</sub> = 0.3 mA	1.1 to 1.3	_		$V_{CC} \times 0.25$	
			I <sub>OL</sub> = 1.7 mA	1.4 to 1.6	_		$V_{CC} \times 0.25$	]
			I <sub>OL</sub> = 3.0 mA	1.65 to 1.95	_		0.45	
			I <sub>OL</sub> = 4.0 mA	2.3 to 2.7	—		0.4	
			I <sub>OL</sub> = 8.0 mA	3.0 to 3.6	_		0.4	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 0 to 3.6 V		0 to 3.6	—	_	±0.1	μA
Power-OFF leakage current	I <sub>OFF</sub>	V <sub>IN</sub> = 0 to 3.6 V, V <sub>OUT</sub> = 0 to 3.6 V		0	—	_	1.0	μA
Quiescent supply current	I <sub>CC</sub>	$V_{IN} = V_{CC}$ or GND		3.6	_	_	1.0	μA

#### 9.2. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C)

Characteristics	Symbol	Test Conditio	n	V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	_		0.9	V <sub>CC</sub>	—	V
				1.1 to 1.3	$V_{CC}  imes 0.70$	—	
				1.4 to 1.6	$V_{CC}  imes 0.65$	—	
				1.65 to 1.95	$V_{CC}  imes 0.65$	—	
				2.3 to 2.7	1.7	—	
				3.0 to 3.6	2.0	_	
Low-level input voltage	VIL	_		0.9	_	GND	V
				1.1 to 1.3	—	$V_{CC} \times 0.30$	
				1.4 to 1.6	_	$V_{CC}  imes 0.35$	
				1.65 to 1.95	_	$V_{CC}  imes 0.35$	
				2.3 to 2.7	—	0.7	
				3.0 to 3.6	—	0.8	
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IL</sub>	I <sub>OH</sub> = -0.02 mA	0.9	0.75	_	V
			I <sub>OH</sub> = -0.3 mA	1.1 to 1.3	$V_{CC}  imes 0.75$	_	
			I <sub>OH</sub> = -1.7 mA	1.4 to 1.6	$V_{CC}  imes 0.75$	_	
			I <sub>OH</sub> = -3.0 mA	1.65 to 1.95	V <sub>CC</sub> -0.45	_	
			I <sub>OH</sub> = -4.0 mA	2.3 to 2.7	2.0	_	
			I <sub>OH</sub> = -8.0 mA	3.0 to 3.6	2.48	_	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub>	I <sub>OL</sub> = 0.02 mA	0.9	_	0.1	V
			I <sub>OL</sub> = 0.3 mA	1.1 to 1.3	_	$V_{CC}  imes 0.25$	
			I <sub>OL</sub> = 1.7 mA	1.4 to 1.6	_	$V_{CC}  imes 0.25$	
			I <sub>OL</sub> = 3.0 mA	1.65 to 1.95	—	0.45	
			I <sub>OL</sub> = 4.0 mA	2.3 to 2.7	_	0.4	
			I <sub>OL</sub> = 8.0 mA	3.0 to 3.6	_	0.4	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 0 to 3.6 V		0 to 3.6	_	±0.5	μA
Power-OFF leakage current	I <sub>OFF</sub>	V <sub>IN</sub> = 0 to 3.6 V, V <sub>OUT</sub> = 0 to 3.6 V		0	—	10.0	μA
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		3.6	_	10.0	μA

#### 9.3. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C)

Characteristics	Symbol	Test Conditio	n	V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	_		0.9	V <sub>CC</sub>	—	V
				1.1 to 1.3	$V_{CC} \times 0.70$	—	
				1.4 to 1.6	$V_{CC} \times 0.65$	—	
				1.65 to 1.95	$V_{CC} \times 0.65$	_	
				2.3 to 2.7	1.7	_	
				3.0 to 3.6	2.0	_	
Low-level input voltage	VIL	—		0.9	—	GND	V
				1.1 to 1.3	—	$V_{CC} \times 0.30$	
				1.4 to 1.6	—	$V_{CC} \times 0.35$	
				1.65 to 1.95	—	$V_{CC} \times 0.35$	
				2.3 to 2.7	—	0.7	
				3.0 to 3.6	_	0.8	
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IL</sub>	I <sub>OH</sub> = -0.02 mA	0.9	0.75	_	V
			I <sub>OH</sub> = -0.3 mA	1.1 to 1.3	$V_{CC}  imes 0.73$	_	
			I <sub>OH</sub> = -1.7 mA	1.4 to 1.6	$V_{CC}  imes 0.73$	_	
			I <sub>OH</sub> = -3.0 mA	1.65 to 1.95	V <sub>CC</sub> -0.5	_	
			I <sub>OH</sub> = -4.0 mA	2.3 to 2.7	1.95	—	
			I <sub>OH</sub> = -8.0 mA	3.0 to 3.6	2.4	_	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub>	I <sub>OL</sub> = 0.02 mA	0.9	—	0.1	V
			I <sub>OL</sub> = 0.3 mA	1.1 to 1.3	—	$V_{CC} \times 0.27$	
			I <sub>OL</sub> = 1.7 mA	1.4 to 1.6	—	$V_{CC} \times 0.27$	
			I <sub>OL</sub> = 3.0 mA	1.65 to 1.95	—	0.5	
			I <sub>OL</sub> = 4.0 mA	2.3 to 2.7	—	0.45	
			I <sub>OL</sub> = 8.0 mA	3.0 to 3.6	—	0.45	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 0 to 3.6 V		0 to 3.6	—	±2.0	μA
Power-OFF leakage current	I <sub>OFF</sub>	V <sub>IN</sub> = 0 to 3.6 V, V <sub>OUT</sub> = 0 to 3.6 V		0	—	80.0	μA
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		3.6	_	80.0	μA

#### 9.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Тур.	Max	Unit
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		R <sub>L</sub> = 1 MΩ	0.9	10	_	20.7	_	ns
				1.1 to 1.3			10.5	18.4	
				1.4 to 1.6		_	6.1	8.5	
				1.65 to 1.95		_	4.5	6.2	
				2.3 to 2.7		_	3.0	3.9	
				3.0 to 3.6		-	2.3	3.1	
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		R <sub>L</sub> = 1 MΩ	0.9	15		22.9	_	ns
				1.1 to 1.3		_	11.5	21.5	
				1.4 to 1.6		-	6.7	9.3	
				1.65 to 1.95		_	4.9	6.9	
				2.3 to 2.7		_	3.2	4.4	
				3.0 to 3.6		_	2.5	3.4	
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		$R_L = 1 M\Omega$	0.9	30	_	30.6	_	ns
				1.1 to 1.3		_	14.8	29.6	
				1.4 to 1.6		_	8.5	13.1	
				1.65 to 1.95		_	6.3	9.2	
				2.3 to 2.7		_	4.3	5.7	
				3.0 to 3.6		-	3.3	4.4	
Input capacitance	C <sub>IN</sub>		_	3.6	_	_	3	_	pF
Power dissipation capacitance	C <sub>PD</sub>	(Note 1)	—	0.9 to 3.6	—		9	_	pF

Note 1:  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.  $I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$ 

### 9.5. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Max	Unit
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>	R <sub>L</sub> = 1 ΜΩ	0.9	10	_	_	ns
			1.1 to 1.3	1	1.0	34.2	
			1.4 to 1.6		1.0	10.0	
			1.65 to 1.95		1.0	6.7	
			2.3 to 2.7	1	1.0	4.4	
			3.0 to 3.6		1.0	3.7	
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>	R <sub>L</sub> = 1 ΜΩ	0.9	15	_	_	ns
			1.1 to 1.3		1.0	37.2	
			1.4 to 1.6		1.0	11.2	
			1.65 to 1.95		1.0	7.1	
			2.3 to 2.7		1.0	5.0	
			3.0 to 3.6		1.0	3.9	
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>	R <sub>L</sub> = 1 ΜΩ	0.9	30	-	_	ns
			1.1 to 1.3		1.0	56.0	
			1.4 to 1.6		1.0	15.9	
			1.65 to 1.95	]	1.0	9.6	
			2.3 to 2.7	]	1.0	6.1	
			3.0 to 3.6		1.0	4.8	

## 9.6. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Max	Unit
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>	R <sub>L</sub> = 1 ΜΩ	0.9	10	_	_	ns
			1.1 to 1.3		1.0	44.8	
			1.4 to 1.6		1.0	11.0	
			1.65 to 1.95		1.0	7.1	
			2.3 to 2.7		1.0	4.8	
			3.0 to 3.6		1.0	4.1	
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>	R <sub>L</sub> = 1 ΜΩ	0.9	15	_	_	ns
			1.1 to 1.3		1.0	47.7	
			1.4 to 1.6		1.0	12.5	
			1.65 to 1.95		1.0	7.6	
			2.3 to 2.7		1.0	5.4	
			3.0 to 3.6		1.0	4.3	
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>	R <sub>L</sub> = 1 ΜΩ	0.9	30	_	_	ns
			1.1 to 1.3		1.0	73.6	
			1.4 to 1.6		1.0	17.8	
			1.65 to 1.95	1	1.0	10.2	
			2.3 to 2.7		1.0	6.6	
			3.0 to 3.6		1.0	5.2	

#### 9.7. AC Waveform

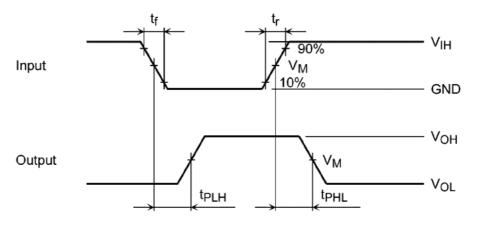


Fig. 9.7.1 t<sub>PLH</sub>, t<sub>PHL</sub>

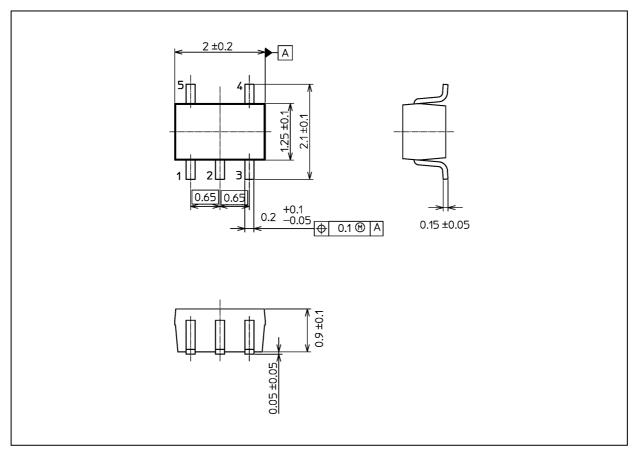
Table 9.7.1	AC Waveform	Symbols
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					-		
	Symbol	V <sub>CC</sub> = 3.3 ± 0.3 V	$\begin{array}{c} V_{\mathrm{CC}} \texttt{=} 2.5 \\ \pm 0.2 \ V \end{array}$	V <sub>CC</sub> = 1.8 ± 0.15 V	V <sub>CC</sub> = 1.5 ± 0.1 V	V <sub>CC</sub> = 1.2 ± 0.1 V	V <sub>CC</sub> = 0.9 V
Input	V <sub>IH</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>
	V <sub>M</sub>	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2
Output	V <sub>M</sub>	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2

### 7UL1G04FU

#### Package Dimensions

Unit: mm



#### Weight: 6.2 mg (typ.)

	Package Name(s)
JEDEC: SOT-353	
Nickname: USV	

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